



TPS22932B

www.ti.com

SLVS802B –AUGUST 2009–REVISED AUGUST 2013

LOW INPUT VOLTAGE, ULTRA-LOW r_{ON} LOAD SWITCH WITH CONFIGURABLE ENABLE LOGIC AND CONTROLLED SLEW-RATE

Check for Samples: [TPS22932B](#)

FEATURES

- Input Voltage: 1.1 V to 3.6 V
- Ultra-Low ON Resistance
 - $r_{ON} = 55\text{ m}\Omega$ at $V_{IN} = 3.6\text{ V}$
 - $r_{ON} = 65\text{ m}\Omega$ at $V_{IN} = 2.5\text{ V}$
 - $r_{ON} = 75\text{ m}\Omega$ at $V_{IN} = 1.8\text{ V}$
 - $r_{ON} = 115\text{ m}\Omega$ at $V_{IN} = 1.2\text{ V}$
- 500-mA Maximum Continuous Switch Current
- Quiescent Current $< 1\text{ }\mu\text{A}$
- Shutdown Current $< 1\text{ }\mu\text{A}$
- Low Control Threshold Allows Use of 1.2-V/1.8-V/2.5-V/3.3-V Logic
- Configurable Enable Logic
- Controlled Slew Rate to Avoid Inrush Currents: 165 μs at 1.8 V
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Six-Terminal Wafer Chip Scale Package (DSBGA)
 - 0.8 mm \times 1.2 mm, 0.4-mm Pitch, 0.5-mm Height

APPLICATIONS

- PDAs
- Cell Phones
- GPS Devices
- MP3 Players
- Digital Cameras
- Peripheral Ports
- Portable Instrumentation

DESCRIPTION

TPS22932B is a low r_{ON} load switch with controlled turn on. It contains an ultra-low r_{ON} P-channel MOSFET that can operate over an input voltage range of 1.1 V to 3.6 V.

The switch is controlled by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and non-inverter. All inputs can be connected to V_{IN} or GND. The control pins can be connected to low voltage GPIOs allowing it to be controlled by whatever 1.2-V, 1.8-V, 2.5-V, or 3.3-V logic signals while keeping extremely low quiescent current.

A 120- Ω on-chip load resistor is available for output quick discharge when the switch is turned off. The rise time (slew rate) of the device is internally controlled to avoid inrush current: the rise time of TPS22932B is 165 μs .

TPS22932B is available in a space-saving 6-terminal DSBGA (YFP with 0.4-mm pitch). The device is characterized for operation over the free-air temperature range of -40°C to 85°C .

| DEVICE | r_{ON} AT 1.8 V (TYP) | SLEW RATE (TYP AT 3.3 V) | QUICK OUTPUT DISCHARGE ⁽¹⁾ | MAX OUTPUT CURRENT | ENABLE |
|-----------|-------------------------|--------------------------|---------------------------------------|--------------------|-------------|
| TPS22932B | 75 m Ω | 165 μs | Yes | 500 mA | Active high |

(1) This feature discharges the output of the switch to ground through a 120- Ω resistor, preventing the output from floating.

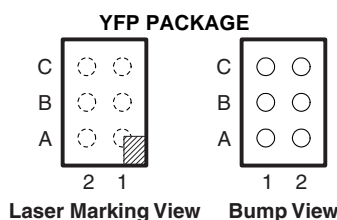


Table 1. TERMINAL ASSIGNMENTS

| | | |
|----------|----------|-----------|
| C | ON2 | ON3 |
| B | ON1 | GND |
| A | V_{IN} | V_{OUT} |
| | 2 | 1 |



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

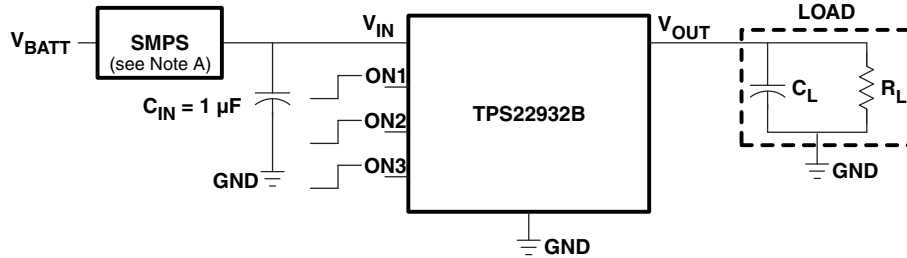
TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

TYPICAL APPLICATION



A. Switched mode power supply

APPLICATION BLOCK DIAGRAM

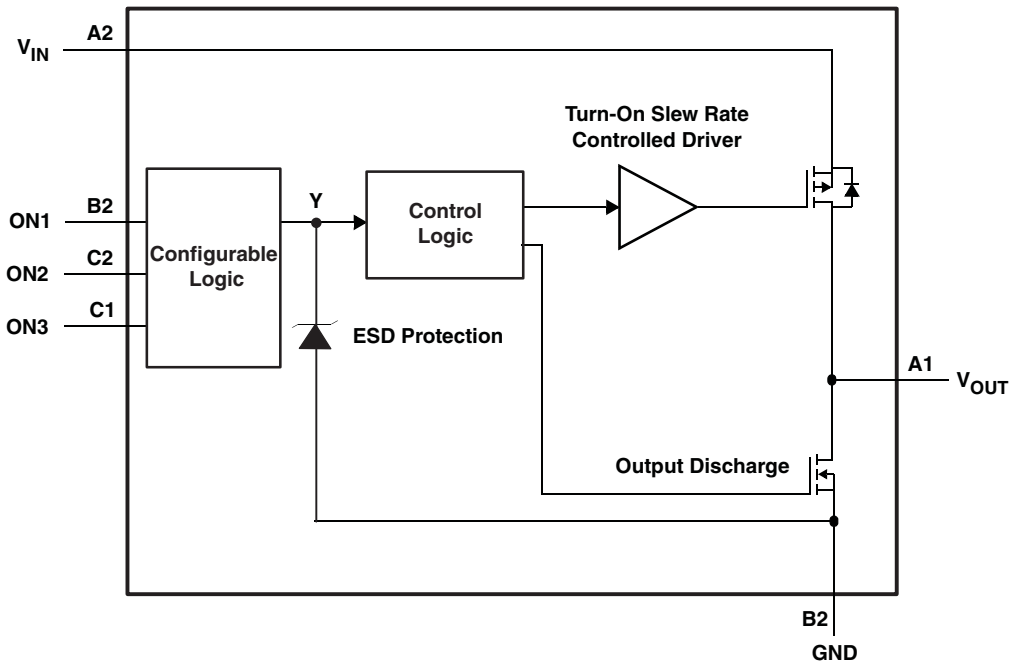


Table 2. CONFIGURABLE LOGIC FUNCTION TABLE

| INPUTS | | | SWITCH CONTROL |
|--------|-----|-----|----------------|
| ON3 | ON2 | ON1 | Y |
| L | L | L | OFF |
| L | L | H | OFF |
| L | H | L | ON |
| L | H | H | ON |
| H | L | L | OFF |
| H | L | H | ON |
| H | H | L | OFF |
| H | H | H | ON |

TERMINAL FUNCTIONS

| TERMINAL | | DESCRIPTION |
|------------|------------------|--|
| NO. | NAME | |
| A1 | V _{OUT} | Switch output |
| A2 | V _{IN} | Switch input, bypass this input with a ceramic capacitor to ground |
| B1 | GND | Ground |
| B2, C2, C1 | ON1, ON2, ON3 | Switch control input, active high - Do not leave floating |

LOGIC DIAGRAM (POSITIVE LOGIC)

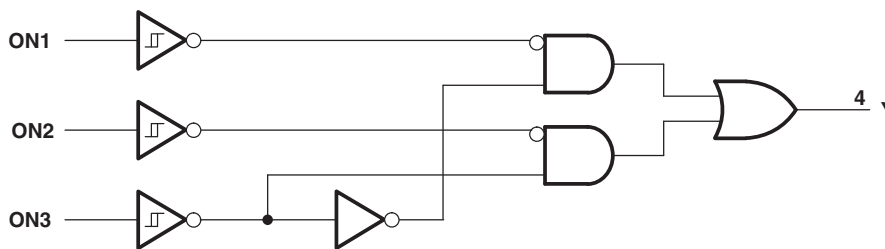


Table 3. FUNCTION SELECTION TABLE

| LOGIC FUNCTION | FIGURE NO. |
|---|--------------------------|
| 2-to-1 data selector | Figure 1 |
| 2-input AND gate | Figure 2 |
| 2-input OR gate with one inverted input | Figure 3 |
| 2-input NAND gate with one inverted input | Figure 3 |
| 2-input AND gate with one inverted input | Figure 4 |
| 2-input NOR gate with one inverted input | Figure 4 |
| 2-input OR gate | Figure 5 |
| Inverter | Figure 6 |
| Noninverted buffer | Figure 7 |

TPS22932B



SLVS802B – AUGUST 2009 – REVISED AUGUST 2013

www.ti.com

LOGIC CONFIGURATIONS

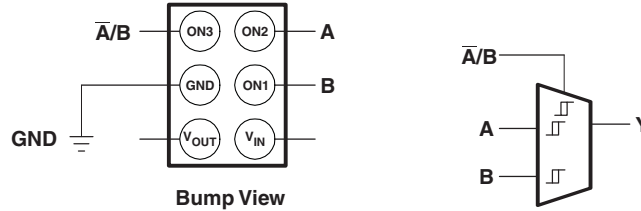


Figure 1. 2-to-1 Data Selector

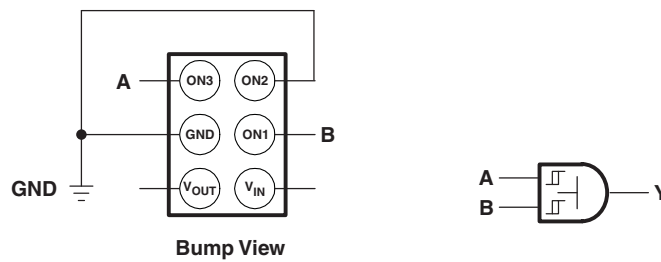
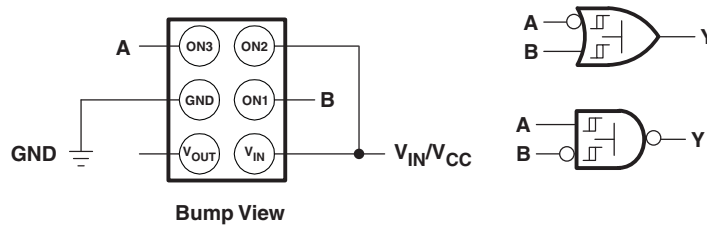
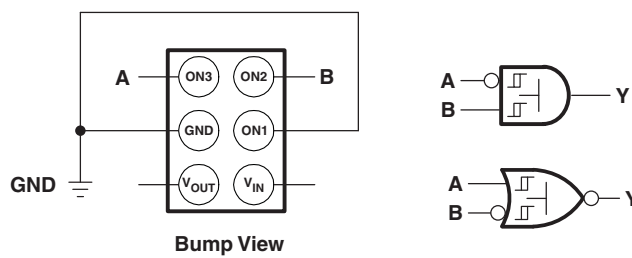


Figure 2. 2-Input AND Gate



**Figure 3. 2-Input OR Gate With One Inverted Input
2-Input NAND Gate With One Inverted Input**



**Figure 4. 2-Input AND Gate With One Inverted Input
2-Input NOR Gate With One Inverted Input**

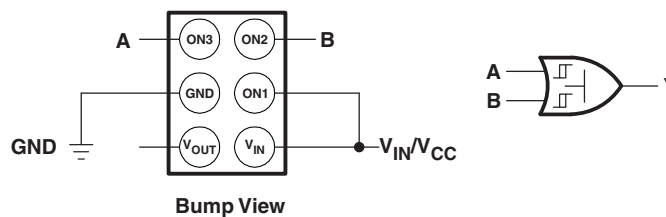


Figure 5. 2-Input OR Gate

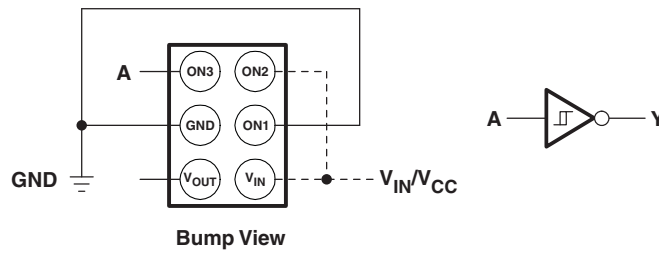


Figure 6. Inverter

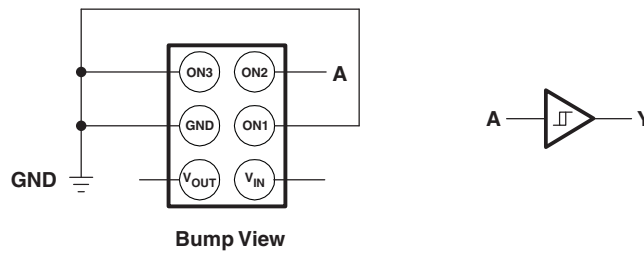


Figure 7. Noninverted Buffer

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

| | | MIN | MAX | UNIT |
|------------|--|----------------------------|----------------|------------------|
| V_{IN} | Input voltage range | -0.3 | 4 | V |
| V_{OUT} | Output voltage range | | $V_{IN} + 0.3$ | V |
| P | Power dissipation at $T_A = 25^\circ\text{C}$ | | 0.8 | W |
| I_{MAX} | Maximum continuous switch current | | 500 | mA |
| T_A | Operating free-air temperature range | -40 | 85 | $^\circ\text{C}$ |
| T_{stg} | Storage temperature range | -65 | 150 | $^\circ\text{C}$ |
| T_{lead} | Maximum lead temperature (10-s soldering time) | | 300 | $^\circ\text{C}$ |
| ESD | Electrostatic discharge protection | Human-Body Model (HBM) | | 2000 |
| | | Charged Device Model (CDM) | | |

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL IMPEDANCE RATINGS

| | | | TYP | UNIT |
|---------------|--|-------------|-----|---------------------------|
| θ_{JA} | Package thermal impedance ⁽¹⁾ | YFP package | 155 | $^\circ\text{C}/\text{W}$ |

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

| | | MIN | MAX | UNIT |
|-----------|----------------------|------------------|----------|---------------|
| I_{OUT} | Output current | | 500 | mA |
| V_{IN} | Input voltage range | 1.1 | 3.6 | V |
| V_{OUT} | Output voltage range | | V_{IN} | |
| C_{IN} | Input capacitor | 1 ⁽¹⁾ | | μF |

(1) See *Application Information*.

TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

ELECTRICAL CHARACTERISTICS

$V_{IN} = 1.1\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | T_A | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---------------------------------------|--|---|-------------------------|-------|-----|--------------------|-----|------|
| I_{IN} | Quiescent current | $I_{OUT} = 0$ | $V_{IN} = 1.1\text{ V}$ | Full | | 140 | 275 | nA |
| | | | $V_{IN} = 1.8\text{ V}$ | | | 280 | 500 | |
| | | | $V_{IN} = 3.6\text{ V}$ | | | 860 | 920 | |
| $I_{IN(OFF)}$ | OFF-state supply current | $V_{ON} = \text{GND}$, $\text{OUT} = \text{Open}$ | $V_{IN} = 1.1\text{ V}$ | Full | | 80 | 225 | nA |
| | | | $V_{IN} = 1.8\text{ V}$ | | | 125 | 300 | |
| | | | $V_{IN} = 3.6\text{ V}$ | | | 340 | 650 | |
| $I_{IN(LEAKAGE)}$ | OFF-state switch current | $V_{ON} = \text{GND}$, $V_{OUT} = 0$ | $V_{IN} = 1.1\text{ V}$ | Full | | 80 | 225 | nA |
| | | | $V_{IN} = 1.8\text{ V}$ | | | 125 | 300 | |
| | | | $V_{IN} = 3.6\text{ V}$ | | | 340 | 650 | |
| r_{ON} | ON-state resistance | $I_{OUT} = -200\text{ mA}$ | $V_{IN} = 3.6\text{ V}$ | 25°C | | 55 | 70 | mΩ |
| | | | | Full | | | 85 | |
| | | | $V_{IN} = 2.5\text{ V}$ | 25°C | | 65 | 80 | |
| | | | | Full | | | 100 | |
| | | | $V_{IN} = 1.8\text{ V}$ | 25°C | | 75 | 90 | |
| | | | | Full | | | 110 | |
| | | | $V_{IN} = 1.2\text{ V}$ | 25°C | | 115 | 130 | |
| | | | | Full | | | 155 | |
| | | | $V_{IN} = 1.1\text{ V}$ | 25°C | | 135 | 150 | |
| | | | | Full | | | 170 | |
| r_{PD} | Output pulldown resistance | $V_{IN} = 3.3\text{ V}$, $V_{ON} = 0$, $I_{OUT} = 30\text{ mA}$ | | 25°C | | 75 | 120 | Ω |
| I_{ON} | ON-state input leakage current | $V_{ON} = 1.1\text{ V to }3.6\text{ V or GND}$ | | Full | | | 1 | μA |
| Control Inputs (ON1, ON2, ON3) | | | | | | | | |
| | Input leakage current | $V_{IN} = 1.1\text{ V to }3.6\text{ V or GND}$ | | Full | | | 1 | μA |
| V_{ON} | Control input voltage | | | Full | | | 3.6 | V |
| V_{T+} | Positive-going input voltage threshold | $V_{IN} = 1.1\text{ V to }1.8\text{ V}$ | | Full | | 0.5 | 0.8 | V |
| | | $V_{IN} = 1.8\text{ V to }3.6\text{ V}$ | | | | 0.6 | 0.9 | |
| V_{T-} | Negative-going input voltage threshold | $V_{IN} = 1.1\text{ V to }1.8\text{ V}$ | | Full | | 0.2 | 0.6 | V |
| | | $V_{IN} = 1.8\text{ V to }3.6\text{ V}$ | | | | 0.3 | 0.7 | |
| ΔV_T | Hysteresis ($V_{T+} - V_{T-}$) | $V_{IN} = 1.1\text{ V to }3.6\text{ V}$ | | Full | | 0.2 | 0.6 | V |

(1) Typical values are at the specified V_{IN} and $T_A = 25^\circ\text{C}$.



SWITCHING CHARACTERISTICS

$V_{IN} = 1.2\text{ V}$, $R_{L_CHIP} = 120\ \Omega$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|---------------------|------------------------|--------------------------|--------------------------|-----|---------------|
| t_{ON} | Turn-ON time | | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | |
| | | $C_L = 1\ \mu\text{F}$ | | | | |
| | | $C_L = 3\ \mu\text{F}$ | | | | |
| t_{OFF} | Turn-OFF time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | | |
| | | | $C_L = 3\ \mu\text{F}$ | | | |
| t_r | V_{OUT} rise time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | | |
| | | | $C_L = 3\ \mu\text{F}$ | | | |
| t_f | V_{OUT} fall time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | | |
| | | | $C_L = 3\ \mu\text{F}$ | | | |

SWITCHING CHARACTERISTICS

$V_{IN} = 1.5\text{ V}$, $R_{L_CHIP} = 120\ \Omega$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|---------------------|------------------------|--------------------------|--------------------------|-----|---------------|
| t_{ON} | Turn-ON time | | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | |
| | | $C_L = 1\ \mu\text{F}$ | | | | |
| | | $C_L = 3\ \mu\text{F}$ | | | | |
| t_{OFF} | Turn-OFF time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | | |
| | | | $C_L = 3\ \mu\text{F}$ | | | |
| t_r | V_{OUT} rise time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | | |
| | | | $C_L = 3\ \mu\text{F}$ | | | |
| t_f | V_{OUT} fall time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | | |
| | | | $C_L = 3\ \mu\text{F}$ | | | |

TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

SWITCHING CHARACTERISTICS

$V_{IN} = 1.8\text{ V}$, $R_{L_CHIP} = 120\ \Omega$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------|---------------------|---------------------|--------------------------|-----|-----|-----|---------------|
| t_{ON} | Turn-ON time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 215 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 240 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 260 | | |
| t_{OFF} | Turn-OFF time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 24 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 60 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 142 | | |
| t_r | V_{OUT} rise time | $R_L = 500$ | $C_L = 0.1\ \mu\text{F}$ | | 165 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 165 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 175 | | |
| t_f | V_{OUT} fall time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 18 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 145 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 440 | | |

SWITCHING CHARACTERISTICS

$V_{IN} = 2.5\text{ V}$, $R_{L_CHIP} = 120\ \Omega$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------|---------------------|---------------------|--------------------------|-----|-----|-----|---------------|
| t_{ON} | Turn-ON time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 185 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 205 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 225 | | |
| t_{OFF} | Turn-OFF time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 2 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 60 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 140 | | |
| t_r | V_{OUT} rise time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 145 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 150 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 160 | | |
| t_f | V_{OUT} fall time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 18 | | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 147 | | |
| | | | $C_L = 3\ \mu\text{F}$ | | 445 | | |



SWITCHING CHARACTERISTICS

$V_{IN} = 3\text{ V}$, $R_{L_CHIP} = 120\ \Omega$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|---------------------|------------------------|--------------------------|--------------------------|-----|---------------|
| t_{ON} | Turn-ON time | | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 170 |
| | | $C_L = 1\ \mu\text{F}$ | | 190 | | |
| | | $C_L = 3\ \mu\text{F}$ | | 210 | | |
| t_{OFF} | Turn-OFF time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 2 | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 60 | |
| | | | $C_L = 3\ \mu\text{F}$ | | 140 | |
| t_r | V_{OUT} rise time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 140 | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 140 | |
| | | | $C_L = 3\ \mu\text{F}$ | | 150 | |
| t_f | V_{OUT} fall time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 17 | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 148 | |
| | | | $C_L = 3\ \mu\text{F}$ | | 450 | |

SWITCHING CHARACTERISTICS

$V_{IN} = 3.3\text{ V}$, $R_{L_CHIP} = 120\ \Omega$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|---------------------|------------------------|--------------------------|--------------------------|-----|---------------|
| t_{ON} | Turn-ON time | | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 160 |
| | | $C_L = 1\ \mu\text{F}$ | | 175 | | |
| | | $C_L = 3\ \mu\text{F}$ | | 195 | | |
| t_{OFF} | Turn-OFF time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 20 | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 55 | |
| | | | $C_L = 3\ \mu\text{F}$ | | 135 | |
| t_r | V_{OUT} rise time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 135 | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 135 | |
| | | | $C_L = 3\ \mu\text{F}$ | | 145 | |
| t_f | V_{OUT} fall time | $R_L = 500\ \Omega$ | $C_L = 0.1\ \mu\text{F}$ | | 17 | μs |
| | | | $C_L = 1\ \mu\text{F}$ | | 148 | |
| | | | $C_L = 3\ \mu\text{F}$ | | 450 | |

TPS22932B



SLVS802B – AUGUST 2009 – REVISED AUGUST 2013

www.ti.com

TYPICAL CHARACTERISTICS

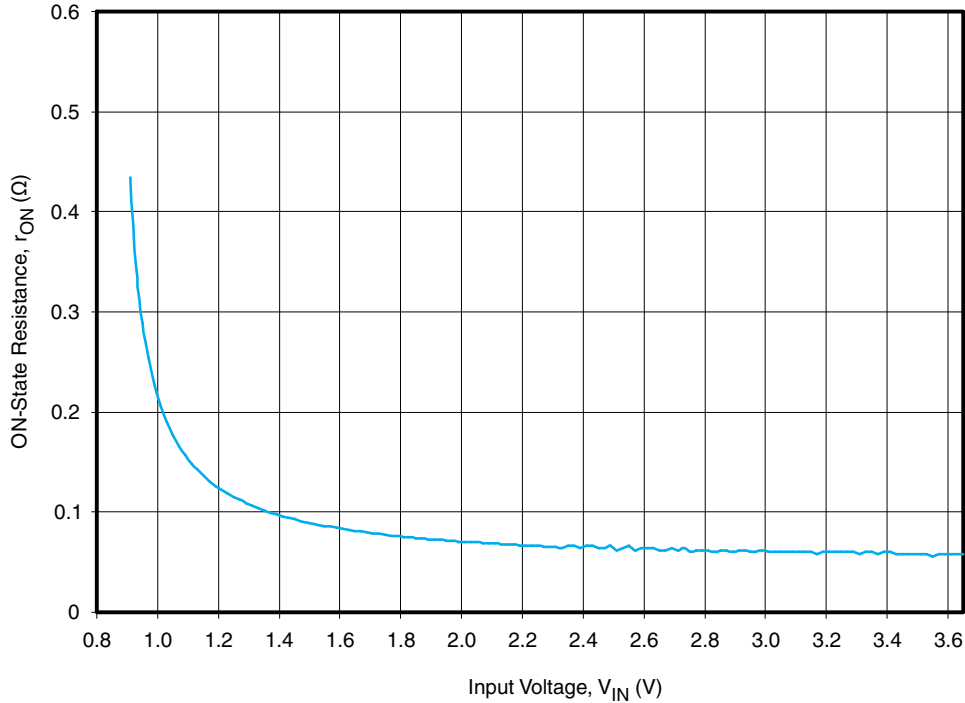


Figure 8. r_{ON} vs V_{IN}

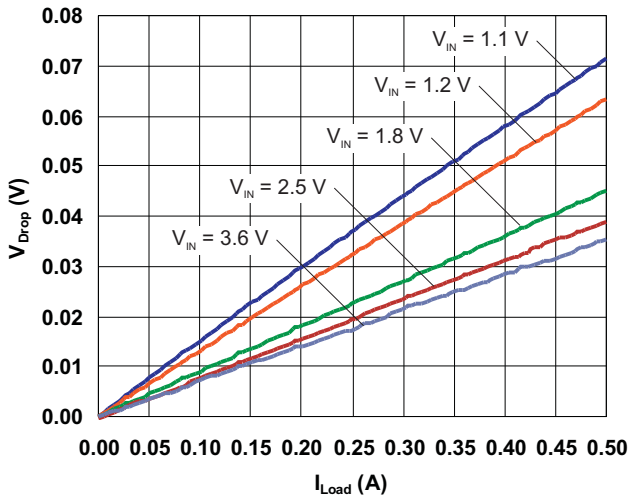


Figure 9. Voltage Drop vs Load Current

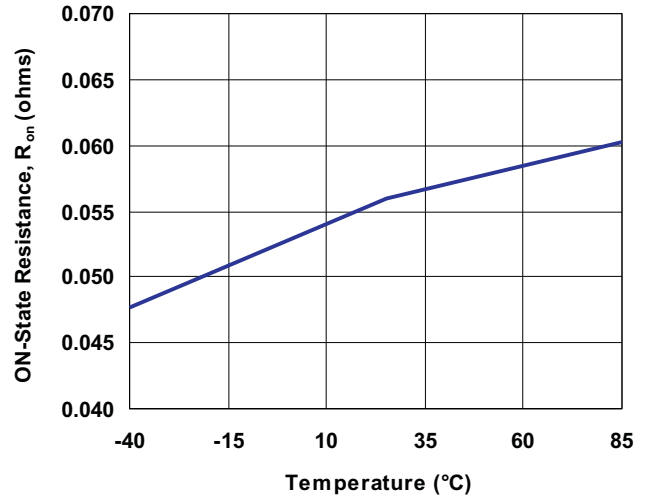


Figure 10. r_{ON} vs T_A ($V_{IN} = 3.3$ V)

TYPICAL CHARACTERISTICS (continued)

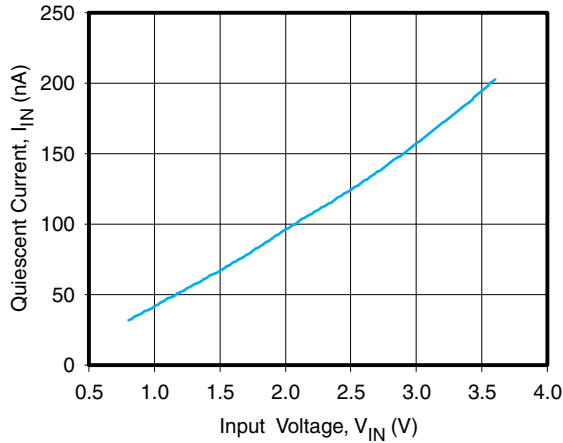


Figure 11. Quiescent Current vs V_{IN}
($ON2 = V_{IN}$, $ON1-ON3 = 0 V$, $I_{out} = 0$)

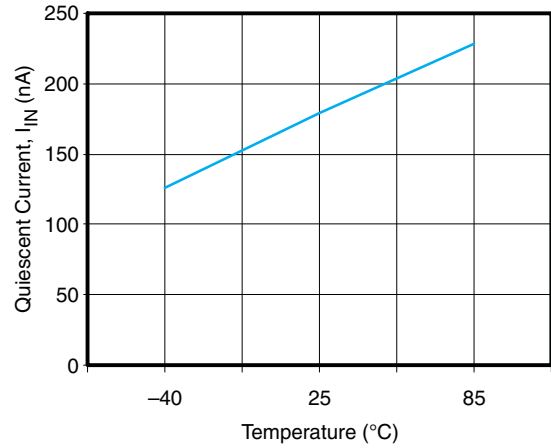


Figure 12. Quiescent Current vs T_A
($V_{IN} = 3.3 V$, $ON2 = V_{IN}$, $ON1-ON3 = 0 V$, $I_{out} = 0$)

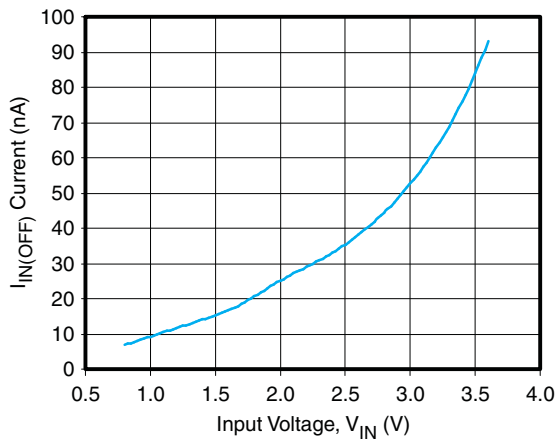


Figure 13. $I_{IN(OFF)}$ vs V_{IN}
($ON1-ON2-ON3 = 0 V$)

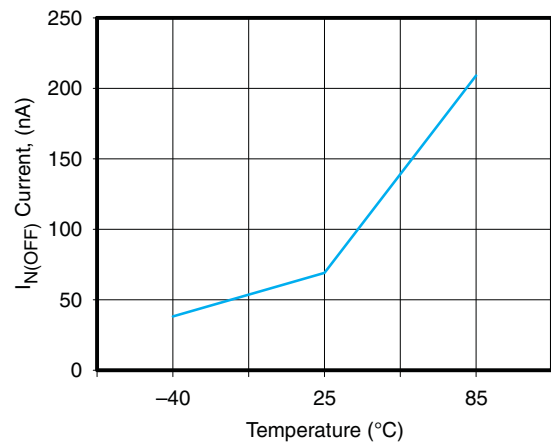


Figure 14. $I_{IN(OFF)}$ vs Temperature
($V_{IN} = 3.3 V$, $ON1-ON2-ON3 = 0 V$)

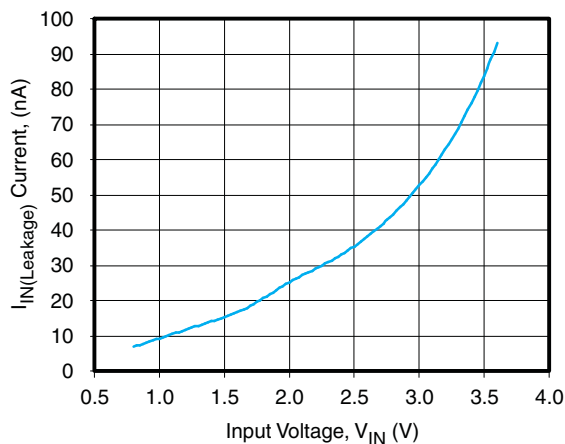


Figure 15. $I_{IN(Leakage)}$ vs V_{IN}
($ON1-ON2-ON3 = 0 V$, $V_{out} = 0$)

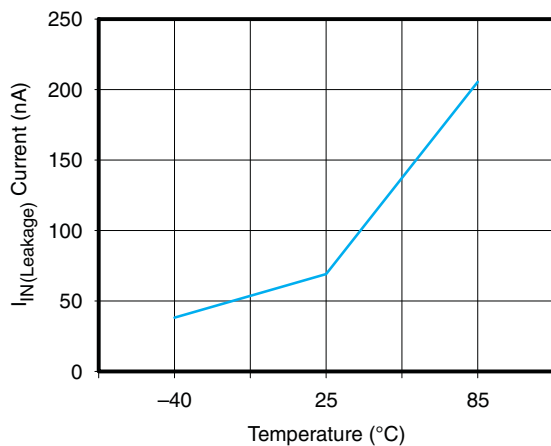


Figure 16. $I_{IN(Leakage)}$ vs Temperature
($V_{IN} = 3.3 V$, $ON1-ON2-ON3 = 0 V$)

TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

TYPICAL CHARACTERISTICS (continued)

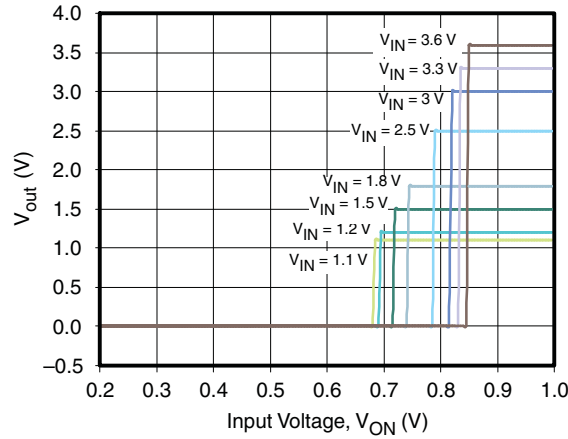


Figure 17. ON-Input Threshold

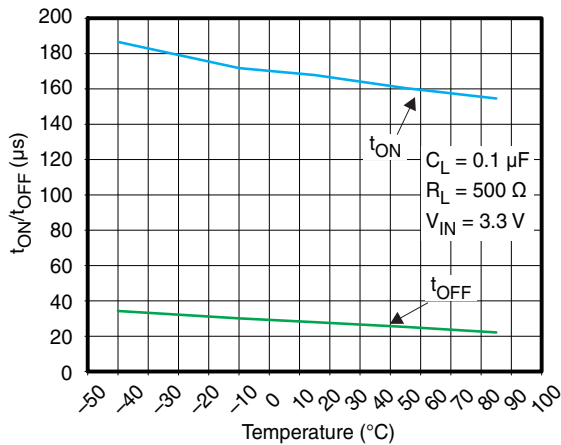


Figure 18. tON/tOFF vs Temperature

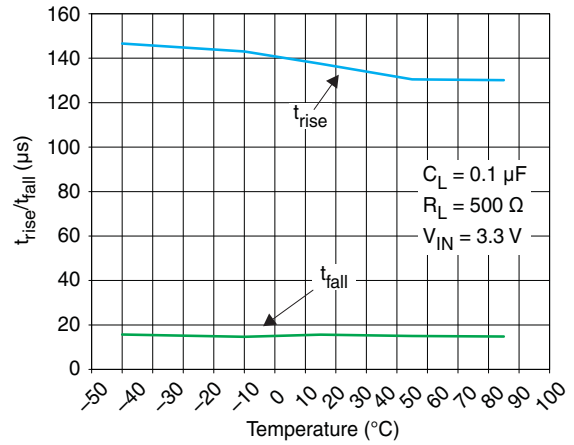


Figure 19. trise/tfall vs Temperature

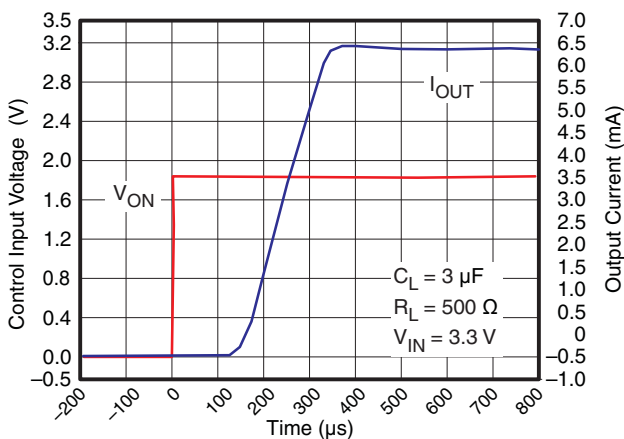


Figure 20. tON Response

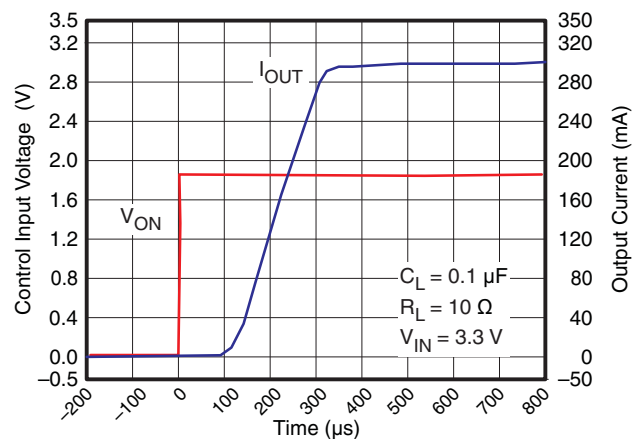


Figure 21. tON Response

TYPICAL CHARACTERISTICS (continued)

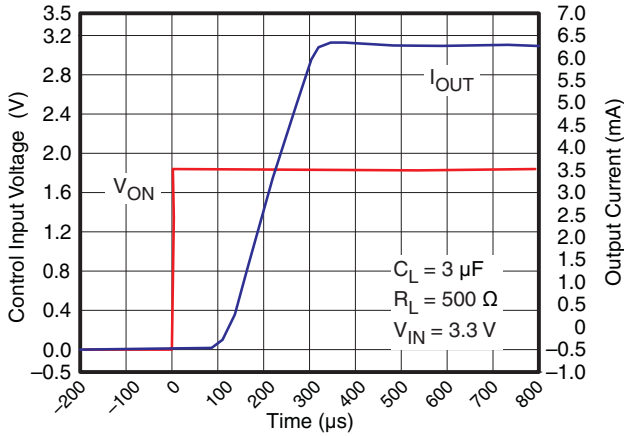


Figure 22. t_{ON} Response

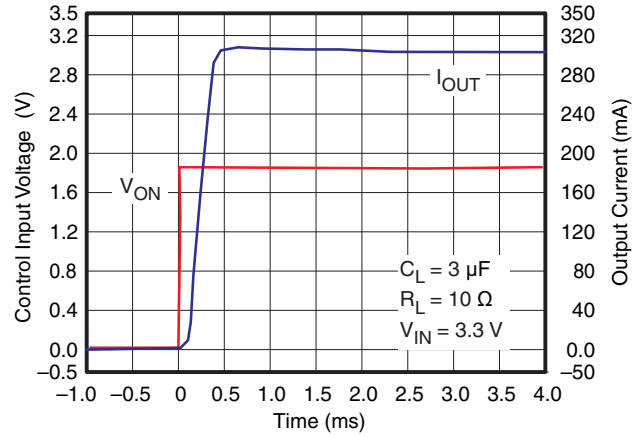


Figure 23. t_{ON} Response

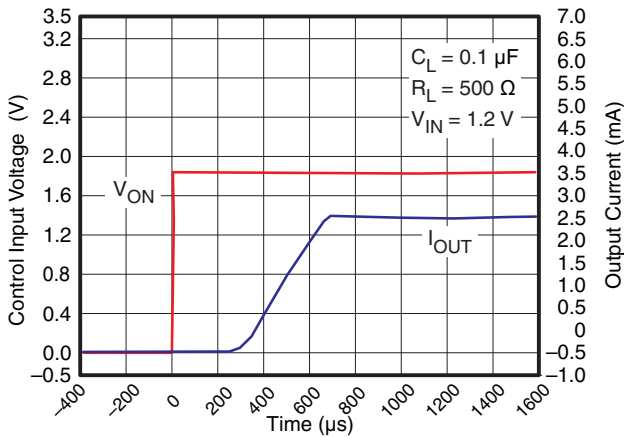


Figure 24. t_{ON} Response

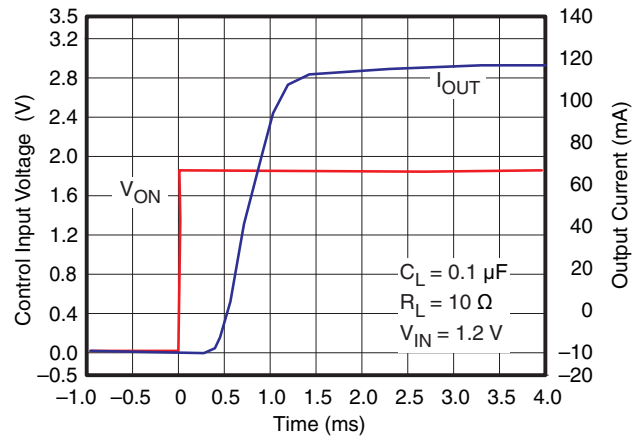


Figure 25. t_{ON} Response

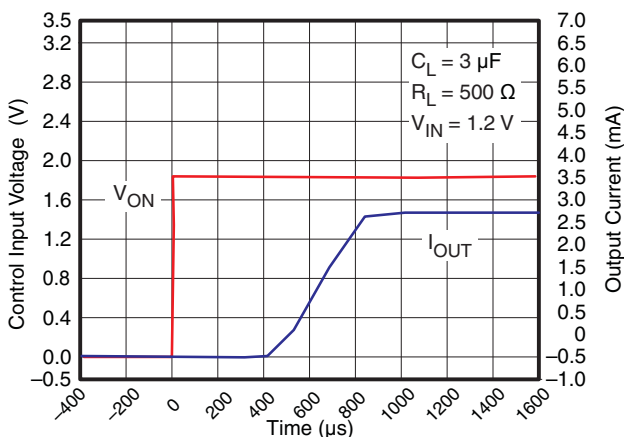


Figure 26. t_{ON} Response

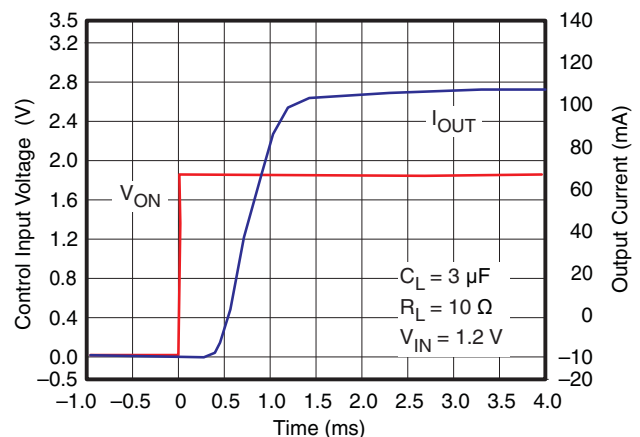


Figure 27. t_{ON} Response

TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

TYPICAL CHARACTERISTICS (continued)

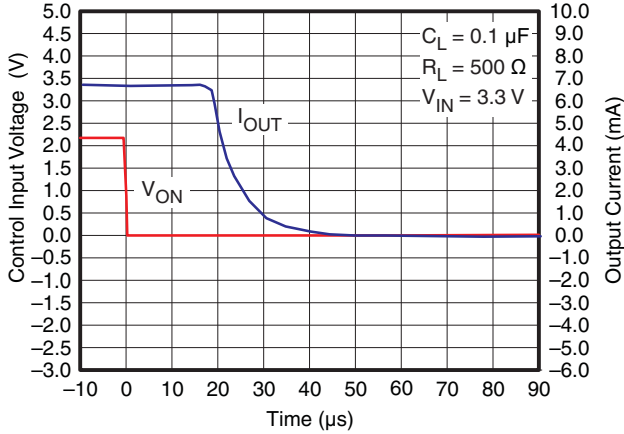


Figure 28. t_{OFF} Response

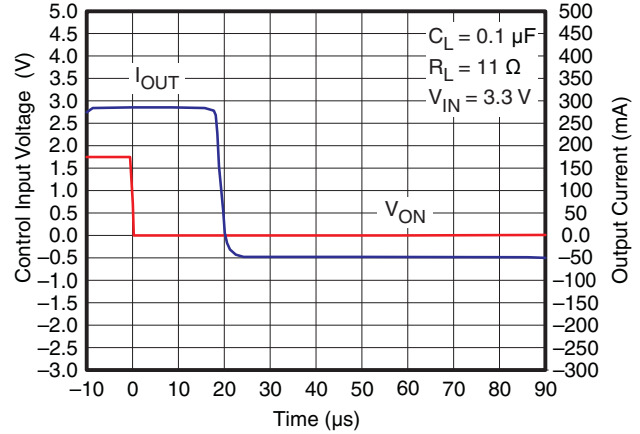


Figure 29. t_{OFF} Response

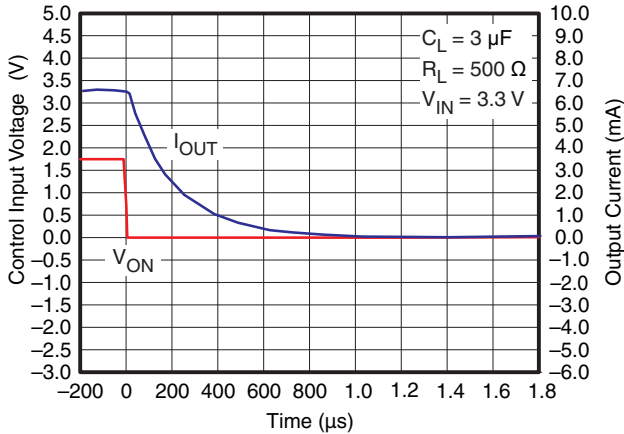


Figure 30. t_{OFF} Response

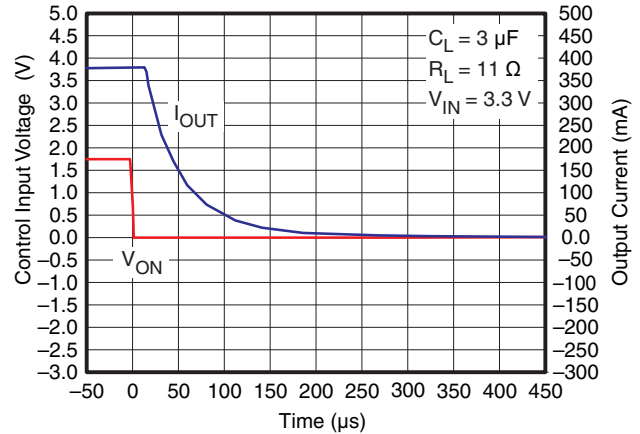


Figure 31. t_{OFF} Response

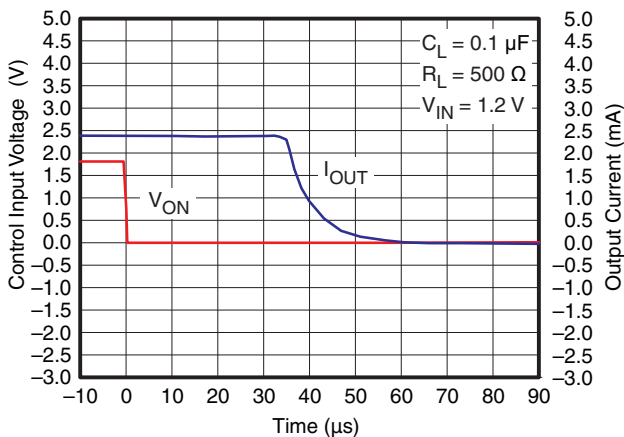


Figure 32. t_{OFF} Response

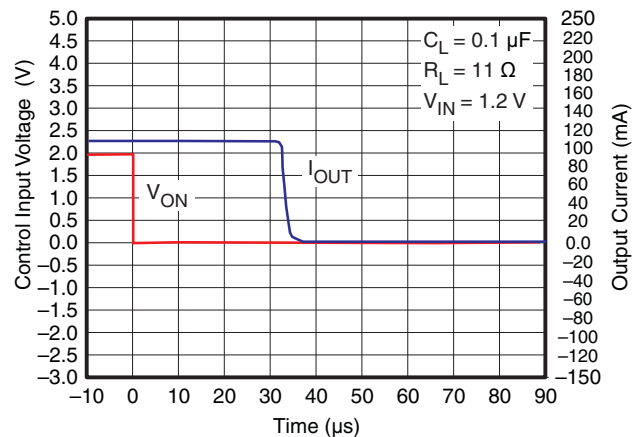


Figure 33. t_{OFF} Response



TYPICAL CHARACTERISTICS (continued)

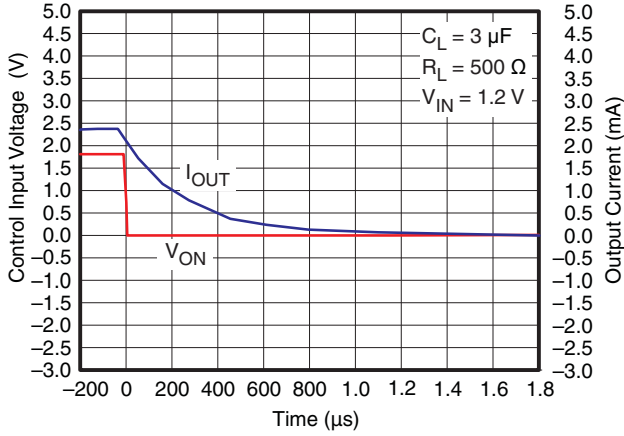


Figure 34. t_{OFF} Response

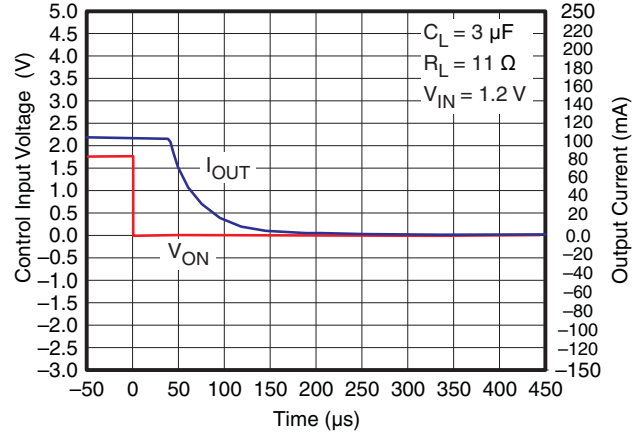


Figure 35. t_{OFF} Response

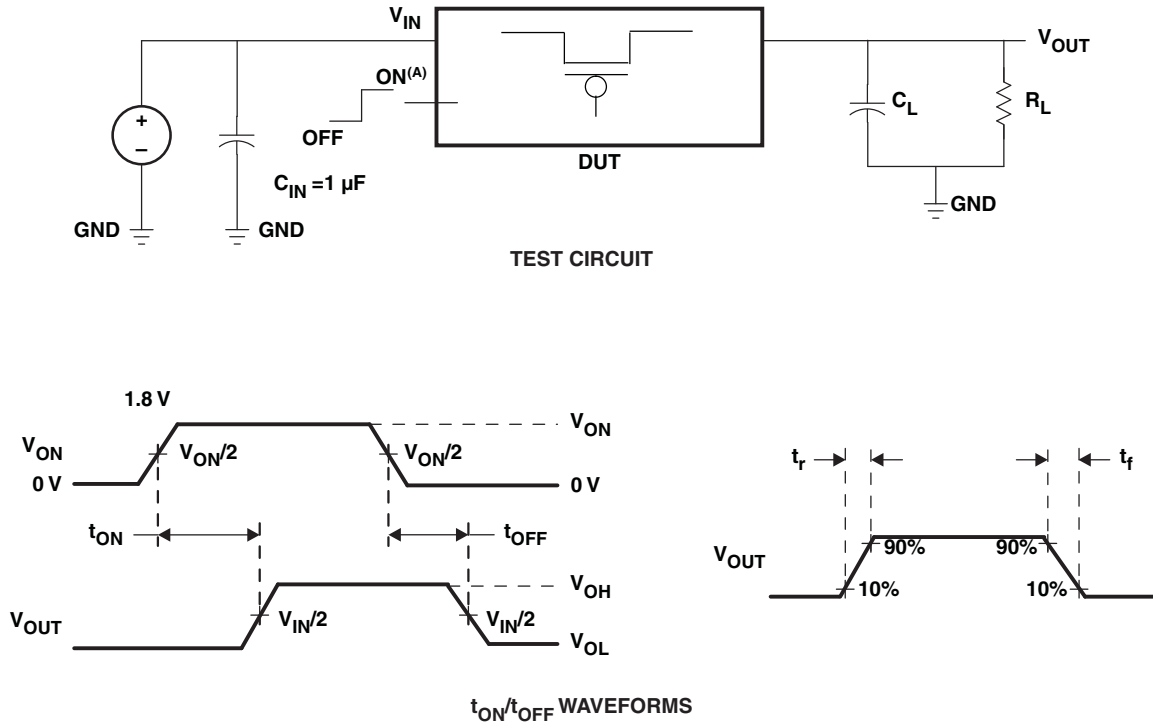
TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

PARAMETER MEASUREMENT INFORMATION



A. t_{rise} and t_{fall} of the control signal is 100 ns.

Figure 36. Test Circuit and t_{ON}/t_{OFF} Waveforms



APPLICATION INFORMATION

ON/OFF Control

The ON pin controls the state of the switch. Activating ON continuously holds the switch in the on state so long as there is no fault. ON is active HI and has a low threshold making it capable of interfacing with low voltage signals. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V or 3.3-V GPIOs.

Input Capacitor

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between V_{IN} and GND. A 1- μ F ceramic capacitor, C_{IN} , placed close to the pins is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop during higher current application. When switching a heavy load, it is recommended to have an input capacitor about 10 or more times higher than the output capacitor in order to avoid any supply drop.

Output Capacitor

Due to the integral body diode in the PMOS switch, a C_{IN} greater than C_L is highly recommended. A C_L greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN} .

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces for V_{IN} , V_{OUT} , and GND will help minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

TPS22932B



SLVS802B –AUGUST 2009–REVISED AUGUST 2013

www.ti.com

REVISION HISTORY

| Changes from Revision A (November 2009) to Revision B | Page |
|--|------|
| • Aligned package description throughout datasheet. | 1 |



PACKAGE OPTION ADDENDUM

www.ti.com

17-May-2014

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPS22932BYFPR | ACTIVE | DSBGA | YFP | 6 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (483 ~ 485) | Samples |
| TPS22932BYFPT | ACTIVE | DSBGA | YFP | 6 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | 483 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

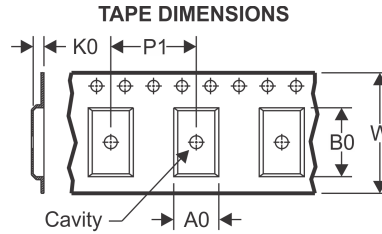
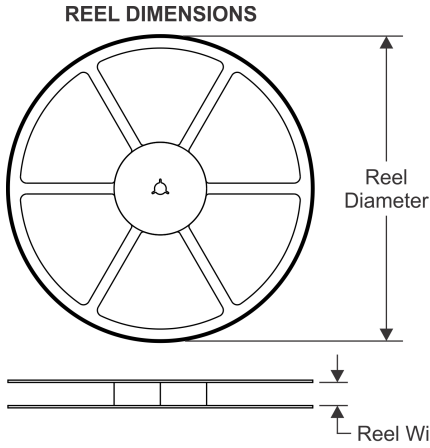


PACKAGE MATERIALS INFORMATION

www.ti.com

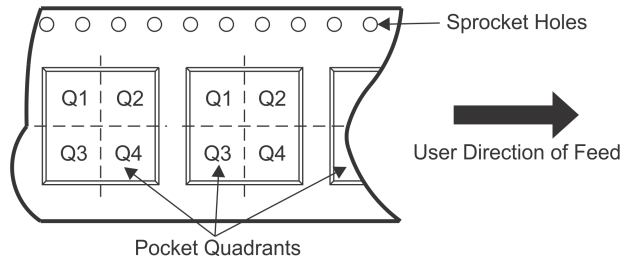
12-Aug-2013

TAPE AND REEL INFORMATION



| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS22932BYFPR | DSBGA | YFP | 6 | 3000 | 180.0 | 8.4 | 0.89 | 1.29 | 0.62 | 4.0 | 8.0 | Q1 |
| TPS22932BYFPT | DSBGA | YFP | 6 | 250 | 180.0 | 8.4 | 0.89 | 1.29 | 0.62 | 4.0 | 8.0 | Q1 |

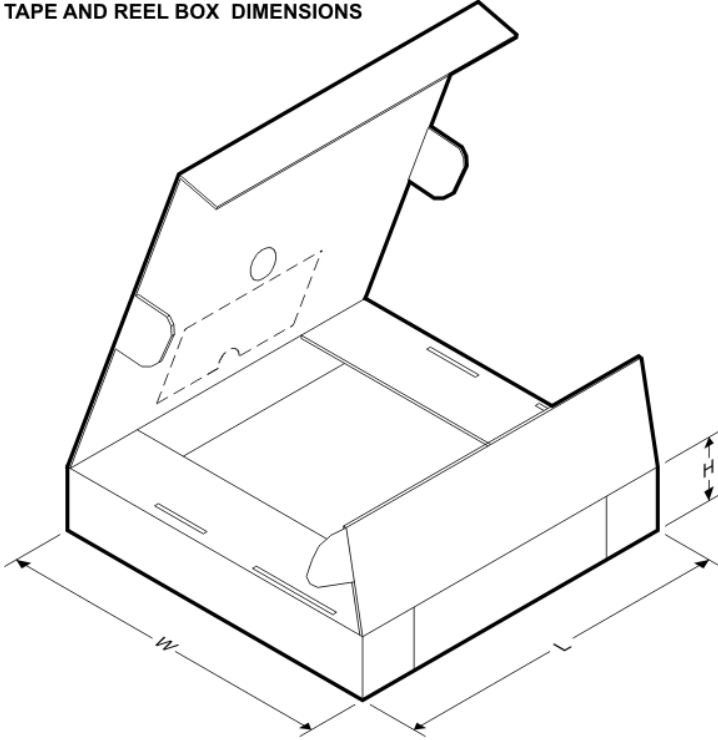


PACKAGE MATERIALS INFORMATION

www.ti.com

12-Aug-2013

TAPE AND REEL BOX DIMENSIONS



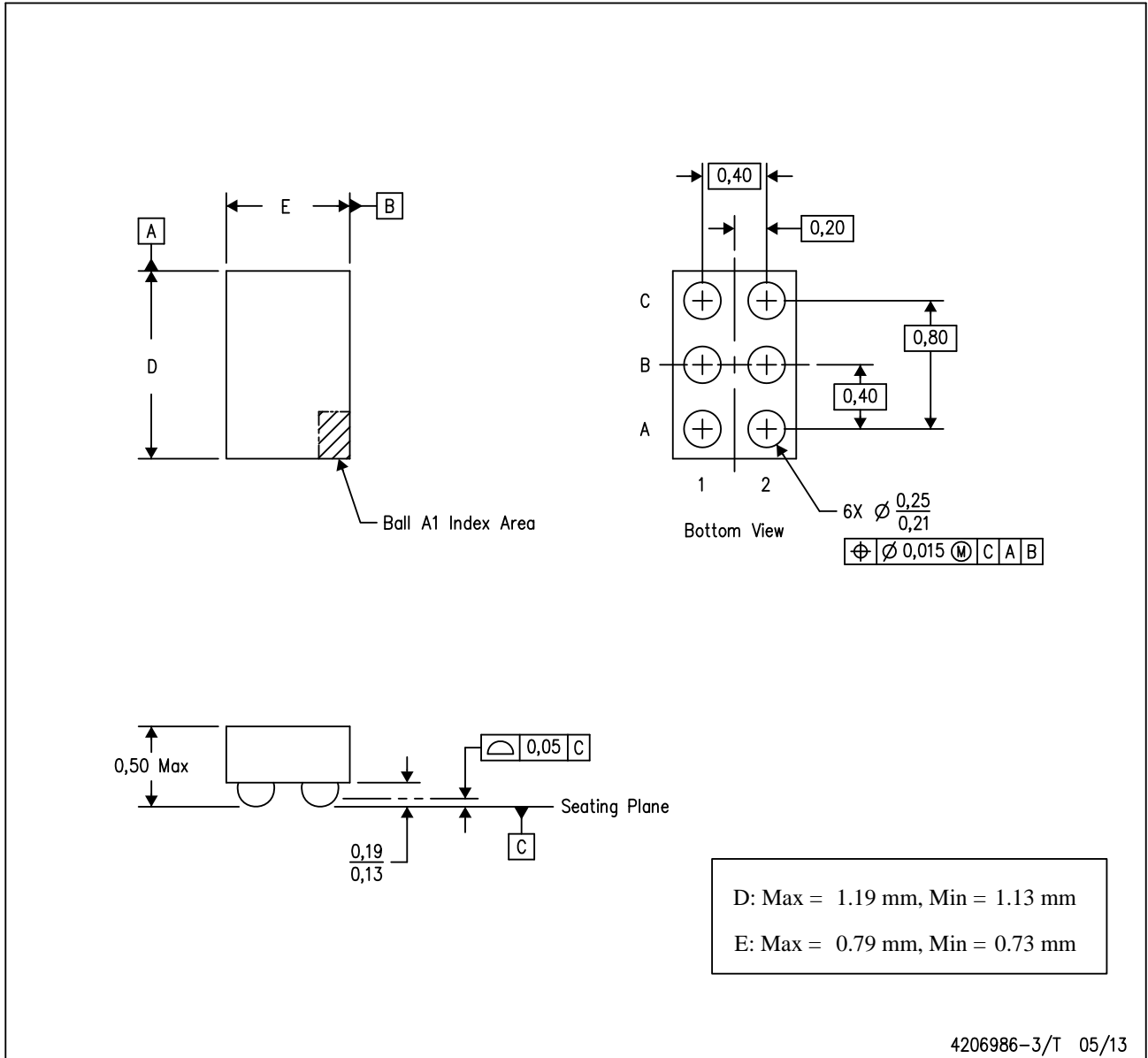
*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS22932BYFPR | DSBGA | YFP | 6 | 3000 | 220.0 | 220.0 | 34.0 |
| TPS22932BYFPT | DSBGA | YFP | 6 | 250 | 220.0 | 220.0 | 34.0 |

MECHANICAL DATA

YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

| | |
|------------------------------|--|
| Audio | www.ti.com/audio |
| Amplifiers | amplifier.ti.com |
| Data Converters | dataconverter.ti.com |
| DLP® Products | www.dlp.com |
| DSP | dsp.ti.com |
| Clocks and Timers | www.ti.com/clocks |
| Interface | interface.ti.com |
| Logic | logic.ti.com |
| Power Mgmt | power.ti.com |
| Microcontrollers | microcontroller.ti.com |
| RFID | www.ti-rfid.com |
| OMAP Applications Processors | www.ti.com/omap |
| Wireless Connectivity | www.ti.com/wirelessconnectivity |

Applications

| | |
|-------------------------------|--|
| Automotive and Transportation | www.ti.com/automotive |
| Communications and Telecom | www.ti.com/communications |
| Computers and Peripherals | www.ti.com/computers |
| Consumer Electronics | www.ti.com/consumer-apps |
| Energy and Lighting | www.ti.com/energy |
| Industrial | www.ti.com/industrial |
| Medical | www.ti.com/medical |
| Security | www.ti.com/security |
| Space, Avionics and Defense | www.ti.com/space-avionics-defense |
| Video and Imaging | www.ti.com/video |

TI E2E Community

e2e.ti.com